## NSN 5961-01-276-2455

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Inclosure Material:
Metal
Overall Length:
1.500 inches
Overall Height:
0.450 inches
Overall Width:
1.000 inches
End Application:
Yellowstone class ad-41; emory s. Land class as; ticonderoga class cg (47)
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
5.00 amperes source cutoff current
Power Rating Per Characteristic:
150.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
50.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter
Special Features:
Weapon system essential; junction pattern arrangement: npn
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

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